

International IOR Rectifier

8ETL06SPbF 8ETL06-1PbF

Ultra-low V_F Hyperfast Rectifier for Discontinuous Mode PFC

Features

- Benchmark Ultra-low Forward Voltage Drop
- Hyperfast Recovery Time
- Low Leakage Current
- 175°C Operating Junction Temperature
- Lead-Free ("PbF" suffix)

$$V_F = 0.96V \text{ typ.}$$

$$I_{F(AV)} = 8Amp$$

$$V_R = 600V$$

Description

State of the art, ultra-low V_F , soft-switching Hyperfast Rectifiers optimized for Discontinuous (Critical) Mode (DCM) Power Factor Correction (PFC).

The minimised conduction loss, optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

The device is also intended for use as a free wheeling diode in power supplies and other power switching applications.

Applications

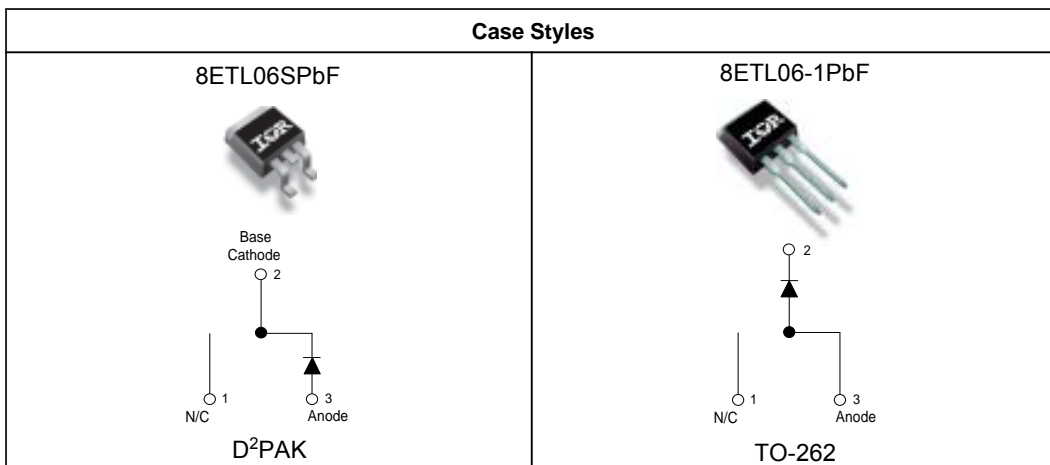
AC-DC SMPS 70W-400W

e.g. Laptop & Printer AC Adaptors, Desktop PC, TV & Monitor, Games units and DVD AC-DC power supplies.

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Absolute Maximum Ratings

Parameters	Max	Units
V_{RRM} Peak Repetitive Reverse Voltage	600	V
$I_{F(AV)}$ Average Rectified Forward Current @ $T_C = 160^\circ C$	8	A
I_{FSM} Non Repetitive Peak Surge Current @ $T_J = 25^\circ C$	175	
I_{FM} Peak Repetitive Forward Current	16	
T_J, T_{STG} Operating Junction and Storage Temperatures	- 65 to 175	$^\circ C$



Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

Parameters	Min	Typ	Max	Units	Test Conditions
V _{BR} , V _F Breakdown Voltage, Blocking Voltage	600	-	-	V	I _R = 100μA
V _F Forward Voltage	-	0.96	1.05	V	I _F = 8A, T _J = 25°C
	-	0.81	0.86	V	I _F = 8A, T _J = 150°C
I _R Reverse Leakage Current	-	0.05	5	μA	V _R = V _R Rated
	-	20	100	μA	T _J = 150°C, V _R = V _R Rated
C _T Junction Capacitance	-	17	-	pF	V _R = 600V
L _S Series Inductance	-	8.0	-	nH	Measured lead to lead 5mm from package body

Dynamic Recovery Characteristics @ T_C = 25°C (unless otherwise specified)

Parameters	Min	Typ	Max	Units	Test Conditions
t _{rr} Reverse Recovery Time	-	60	100	ns	I _F = 1A, di _F /dt = 100A/μs, V _R = 30V
	-	150	250		I _F = 8A, di _F /dt = 100A/μs, V _R = 30V
	-	170	-		T _J = 25°C
	-	250	-		T _J = 125°C
I _{RRM} Peak Recovery Current	-	15	-	A	T _J = 25°C
	-	20	-		T _J = 125°C
Q _{rr} Reverse Recovery Charge	-	1.3	-	μC	T _J = 25°C
	-	2.6	-		T _J = 125°C

I_F = 8A
di_F/dt = 200A/μs
V_R = 390V

Thermal - Mechanical Characteristics

Parameters	Min	Typ	Max	Units
T _J Max. Junction Temperature Range	- 65	-	175	°C
T _{Stg} Max. Storage Temperature Range	- 65	-	175	°C
R _{thJC} Thermal Resistance, Junction to Case Per Leg	-	1.4	2	°C/W
R _{thJA} ① Thermal Resistance, Junction to Ambient Per Leg	-	-	70	
R _{thCS} ② Thermal Resistance, Case to Heatsink	-	0.5	-	
Weight	-	2.0	-	g
	-	0.07	-	(oz)
Mounting Torque	6.0	-	12	Kg-cm
	5.0	-	10	lbf.in
Marking Device	8ETL06S		Case style D ² Pak	
	8ETL06-1		Case style TO-262	

① Typical Socket Mount

② Mounting Surface, Flat, Smooth and Greased

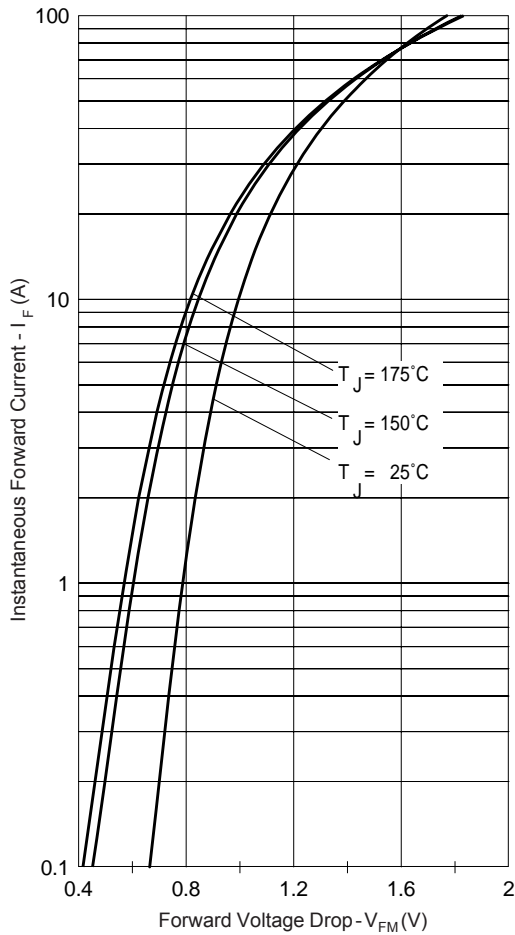


Fig. 1 - Typical Forward Voltage Drop Characteristics

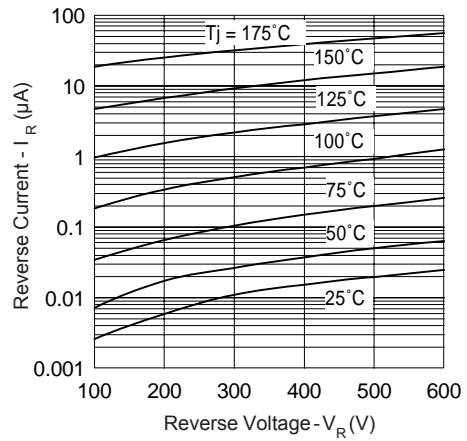


Fig. 2 - Typical Values Of Reverse Current Vs. Reverse Voltage

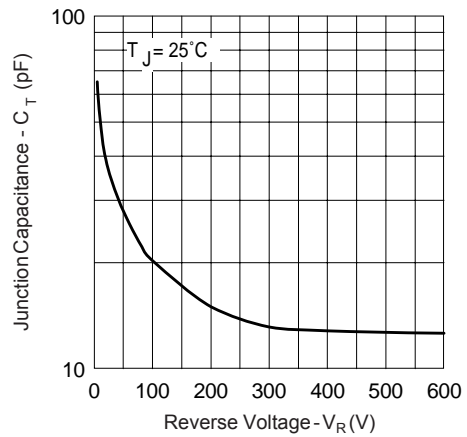


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

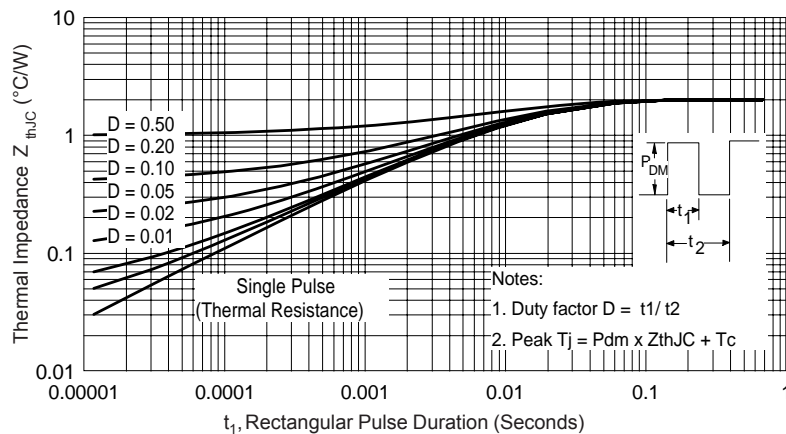


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics

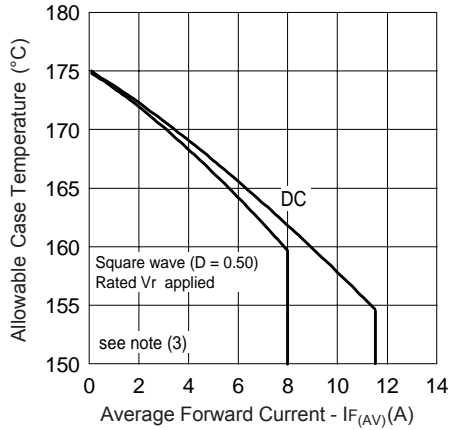


Fig. 5 - Max. Allowable Case Temperature Vs. Average Forward Current

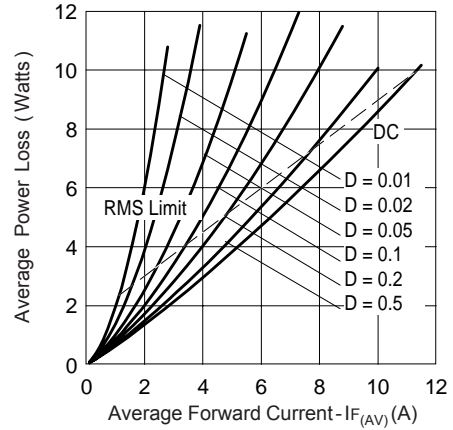


Fig. 6 - Forward Power Loss Characteristics

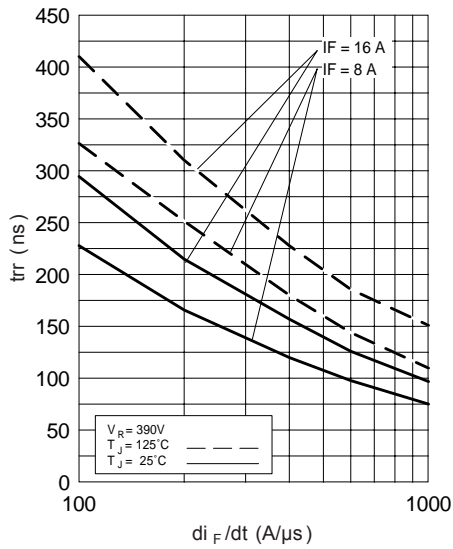


Fig. 7 - Typical Reverse Recovery vs. di_F/dt

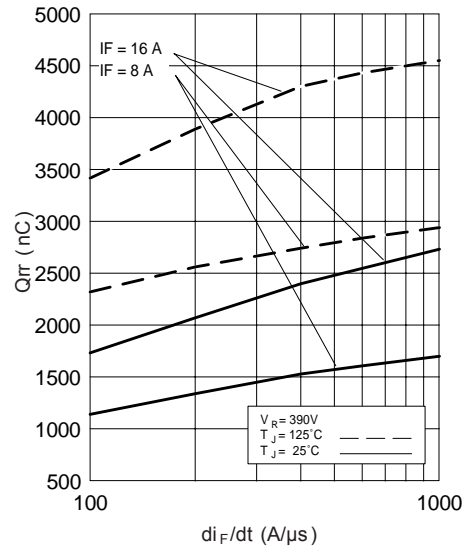


Fig. 8 - Typical Stored Charge vs. di_F/dt

(3) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; Pd = Forward Power Loss = $I_{F(AV)} \times V_{FM} @ (I_{F(AV)}/D)$ (see Fig. 8);
 Pd_{REV} = Inverse Power Loss = $V_{R1} \times I_{R1} (1 - D)$; $I_{R1} @ V_{R1}$ = rated V_R

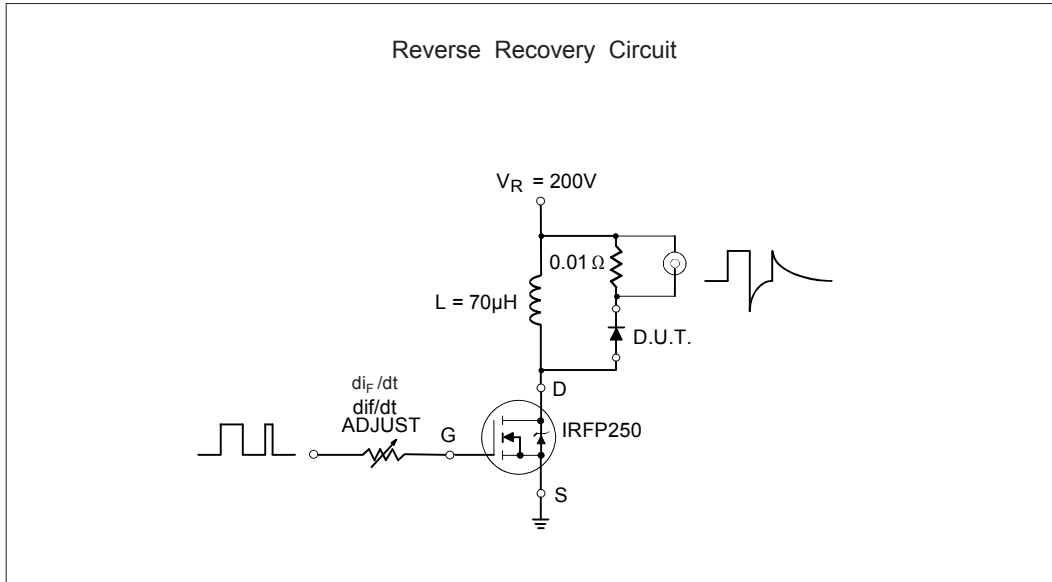


Fig. 9- Reverse Recovery Parameter Test Circuit

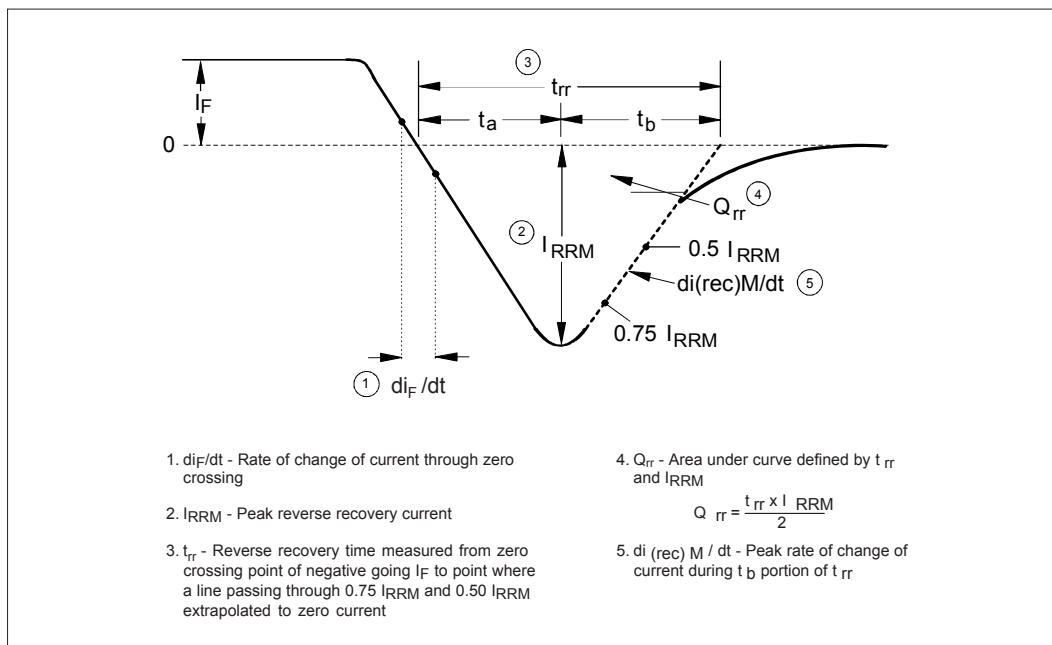
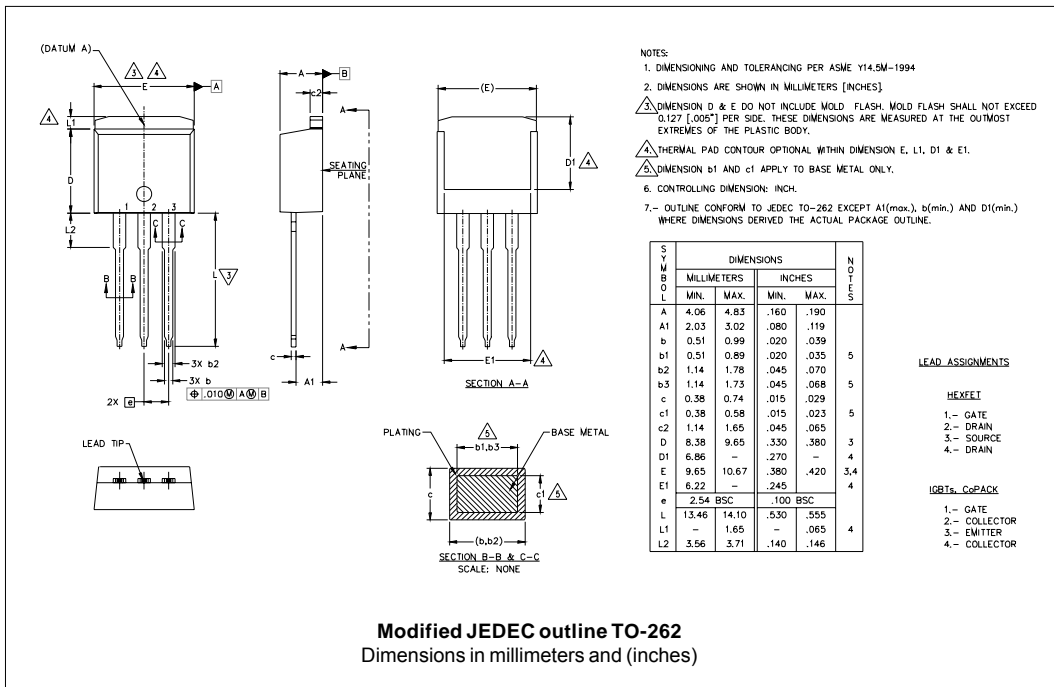
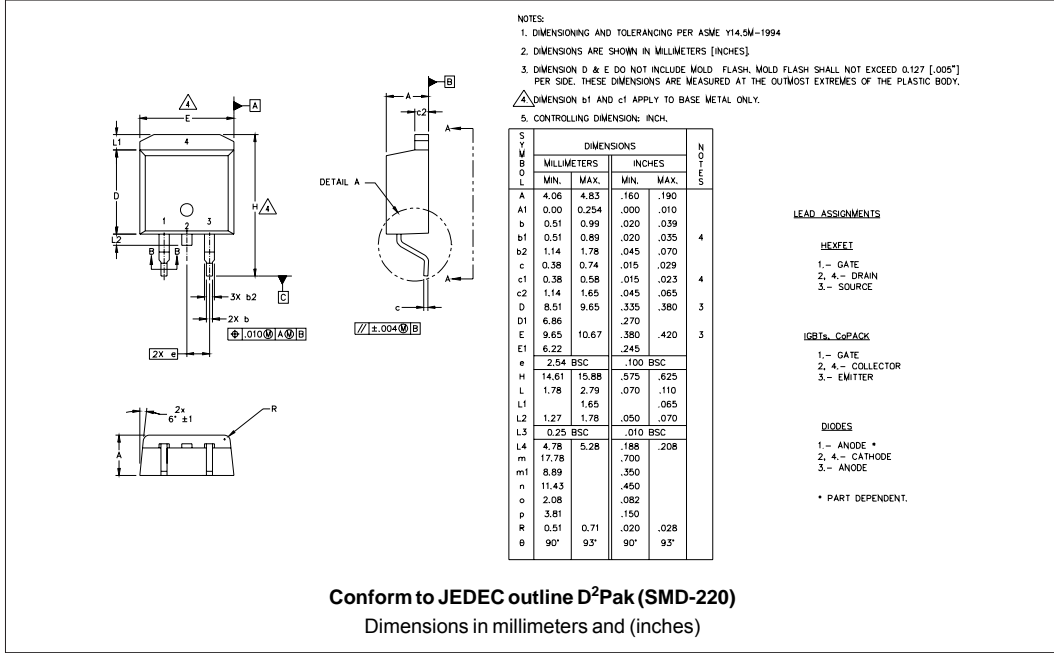
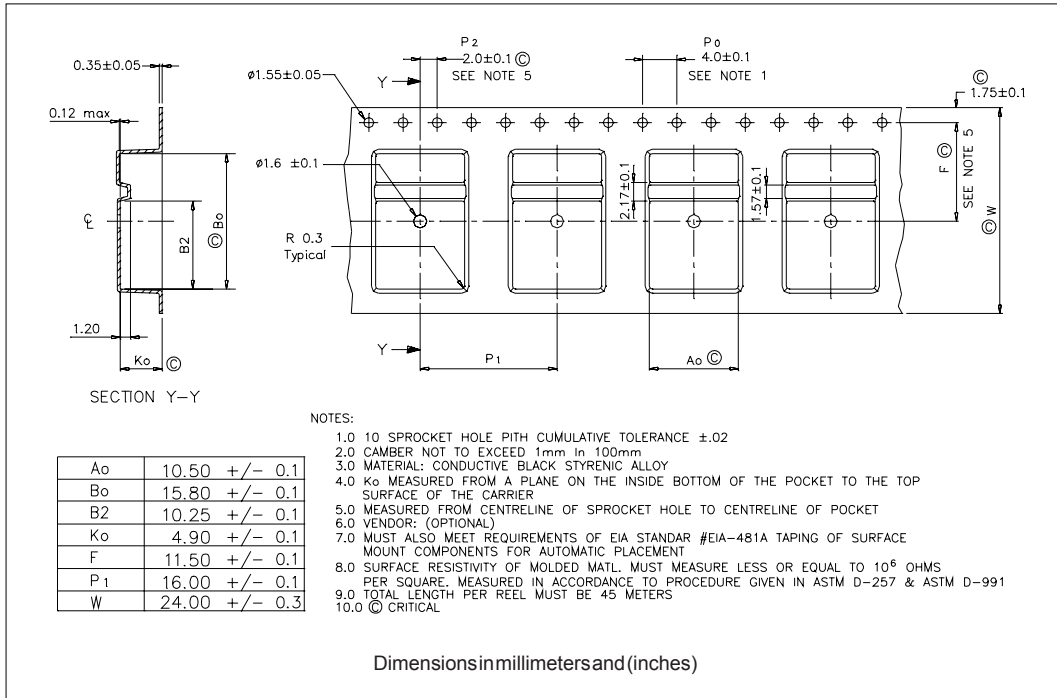


Fig. 10 - Reverse Recovery Waveform and Definitions

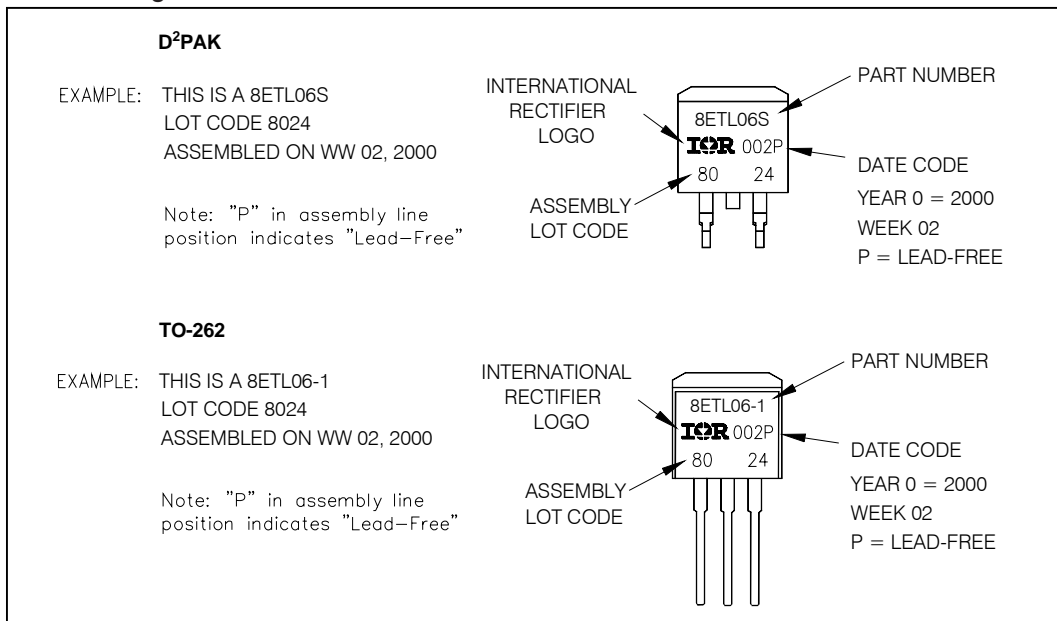
Outline Table



Tape & Reel Information



Part Marking Information



Ordering Information Table

Device Code																	
	<table border="1" style="margin: auto;"> <tr> <td style="padding: 5px;">8</td> <td style="padding: 5px;">E</td> <td style="padding: 5px;">T</td> <td style="padding: 5px;">L</td> <td style="padding: 5px;">06</td> <td style="padding: 5px;">S</td> <td style="padding: 5px;">TRL</td> <td style="padding: 5px;">PbF</td> </tr> <tr> <td style="text-align: center;">①</td> <td style="text-align: center;">②</td> <td style="text-align: center;">③</td> <td style="text-align: center;">④</td> <td style="text-align: center;">⑤</td> <td style="text-align: center;">⑥</td> <td style="text-align: center;">⑦</td> <td style="text-align: center;">⑧</td> </tr> </table>	8	E	T	L	06	S	TRL	PbF	①	②	③	④	⑤	⑥	⑦	⑧
8	E	T	L	06	S	TRL	PbF										
①	②	③	④	⑤	⑥	⑦	⑧										
1	- Current Rating (8A)																
2	- E = Single Diode																
3	- T = TO-220, D ² Pak																
4	- L = Ultra-low V _F HyperFast Recovery																
5	- Voltage Rating (06 = 600V)																
6	- <ul style="list-style-type: none"> • S = D²Pak • -1 = TO-262 																
7	- <ul style="list-style-type: none"> • none = Tube (50 pieces) • TRL = Tape & Reel (Left Oriented, for D²PAK package) • TRR = Tape & Reel (Right Oriented, for D²PAK package) 																
8	- <ul style="list-style-type: none"> • none = Standard Production • PbF = Lead-Free 																

Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level and Lead-Free.
Qualification Standards can be found on IR's Web site.

International
IR Rectifier

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